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## Experimental realization of superconducting quantum interference devices with topological insulator junctions

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We demonstrate topological insulator ( $\text{Bi}_2\text{Te}_3$ ) dc SQUIDS, based on superconducting Nb leads coupled to nano-fabricated Nb- $\text{Bi}_2\text{Te}_3$ -Nb Josephson junctions. The high reproducibility and controllability of the fabrication process allow the creation of dc SQUIDS with parameters that are in agreement with design values. Clear critical current modulation of both the junctions and the SQUID with applied magnetic fields have been observed. We show that the SQUIDS have a periodicity in the voltage-flux characteristic of  $\Phi_0$  of relevance to the ongoing pursuit of realizing interferometers for the detection of Majorana fermions in superconductor—topological insulator structures. © 2012 American Institute of Physics. [doi:10.1063/1.3686150]

A three-dimensional topological insulator is an insulator in the bulk but has conducting surface states that can be described by means of a Dirac cone in which the spin is locked to the electron momentum.<sup>1–10</sup> Electrons with opposite spin have opposite momenta, which suppresses backscattering, rendering these materials interesting for low power electronic devices. Combining the helical Dirac fermions with a superconductor<sup>11–13</sup> may lead to the artificial creation of the elusive Majorana fermion.<sup>14</sup> In the search for the Majorana fermion, efforts have been made to contact a topological insulator (TI) to a superconductor (S). Supercurrents in S-TI-S junctions have been reported.<sup>15–17</sup> The combined evidence for a ballistic Josephson supercurrent and the presence of topological surface states show that topological Josephson junctions can be made, despite the presence of a conductivity shunt through the bulk of the TI crystal.<sup>17</sup>

In this letter, we demonstrate dc SQUIDS consisting of Josephson junctions with topological insulator surface states as barrier layer. These interference devices potentially serve as a basis to detect the Majorana fermion. Majorana bound states may appear in the vortex of a topological superconductor and at S-TI interfaces.<sup>11,13</sup> In the latter, time reversal symmetry in the topological insulator needs to be broken, for example, by incorporating a magnetic insulator layer or by applying an external magnetic field. Intriguing devices are proposed to identify the appearance of this exotic particle.<sup>11–13,18</sup> Since the Majorana fermion is charge neutral and is a zero energy state, most proposals rely upon quantum interference devices. For example, a current-phase relationship with a  $4\pi$  periodicity<sup>11</sup> might result from the interplay between the Majorana fermion and a superconductor. We therefore study the current-phase relationship of the topological dc SQUID.

Figure 1 shows two superconductor Nb—topological insulator  $\text{Bi}_2\text{Te}_3$  dc SQUIDS fabricated on one  $\text{Bi}_2\text{Te}_3$  flake. We have fabricated polycrystalline  $\text{Bi}_2\text{Te}_3$  samples with a common  $c$ -axis orientation using the Czochralski method as described elsewhere.<sup>19</sup> Using mechanical exfoliation,  $\text{Bi}_2\text{Te}_3$  flakes ranging in thickness from 30 nm to 1  $\mu\text{m}$  are transferred to a Si substrate. The  $\text{Bi}_2\text{Te}_3$  flakes are smooth on the nm scale over areas of several  $\mu\text{m}^2$ . Figure 2 shows an atomic force microscopy image of the surface of a typical  $\text{Bi}_2\text{Te}_3$  flake, revealing the 1.0 nm quintuple unit cell layers of  $\text{Bi}_2\text{Te}_3$ . After exfoliation, a superconducting ( $T_C = 9$  K) Nb-layer (200 nm) is sputter deposited with a 5 nm Pd layer deposited *in situ* on top to protect the Nb against oxidation. Electrodes are defined by photolithography. The Nb on top of the  $\text{Bi}_2\text{Te}_3$  flake makes a strong superconducting contact with the Nb on the substrate. Finally, nanojunctions are defined by lift-off e-beam lithography and sputter deposition of Nb. The substrate is slightly conducting ( $\rho = 5 \Omega\text{cm}$ ) at room temperature to increase the resolution of e-beam lithography but is completely insulating at low temperatures.

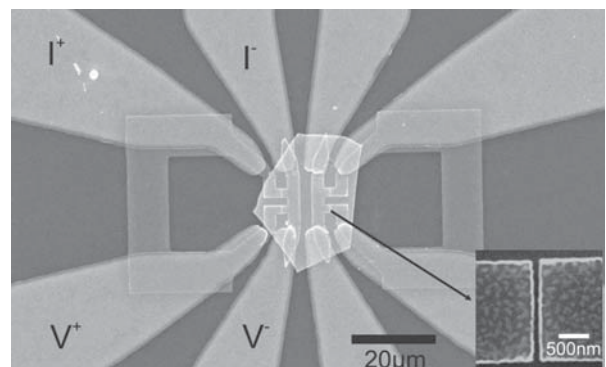


FIG. 1. Scanning electron microscopy image of dc SQUIDS with topological insulator nano junctions. Two SQUIDS with junctions having a separation length  $l = 120$  nm are designed on an exfoliated  $\text{Bi}_2\text{Te}_3$  (200 nm height) flake. The two Nb arms are differently sized resulting in an asymmetric SQUID. Nb is sputter deposited and defined by e-beam lithography. Inset shows a Josephson junction.

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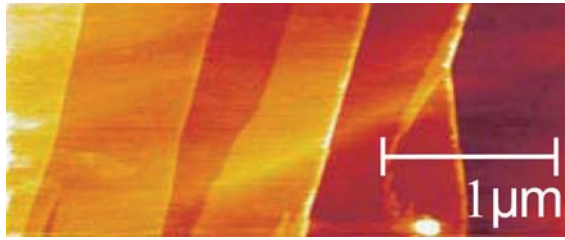


FIG. 2. (Color online) Atomic force microscopy image of an exfoliated  $\text{Bi}_2\text{Te}_3$  surface. The step edges are 1.0 nm high, corresponding to the  $\text{Bi}_2\text{Te}_3$  quintuple unit cell. These nanometer flat surfaces span an area up to  $50 \times 50 \mu\text{m}^2$ .

Prior to deposition, *in situ* Ar-ion etching is performed in order to make transparent contacts. It is found that Ar etching roughens the  $\text{Bi}_2\text{Te}_3$  surface, probably by preferential etching, but 2 min etching with a substrate bias voltage of 50 V leaves a  $\text{Bi}_2\text{Te}_3$  surface with 1-2 nm roughness and a transparent contact. Throughout the fabrication process, the  $\text{Bi}_2\text{Te}_3$  surface in between the Nb leads has only been covered by resist, leaving the surface of the junction barrier layer unaffected by Ar-ion etching and deposition steps. Two separate electrodes connected by Nb over the  $\text{Bi}_2\text{Te}_3$  flake, for example, the positive current and voltage leads, have a superconducting contact with a critical current exceeding 30 mA, ensuring a large supercurrent through all layers.

We have designed two SQUIDs on one  $\text{Bi}_2\text{Te}_3$  flake (200 nm height), see Fig. 1. The nanojunctions are  $2 \mu\text{m}$  wide and have a length  $l = 120 \text{ nm}$ . The inductance ratio between the two arms is about  $\lambda = 0.2$ . In a square washer approximation,<sup>20</sup> the total effective area of the SQUID is  $920 \mu\text{m}^2$ , and the estimated inductance is  $46 \text{ pH}$ . Both SQUIDs showed similar behavior, but in the rest of the paper, we focus on the left SQUID of Fig. 1.

Below 6 K, the superconducting proximity effect induces a Josephson supercurrent through the junctions and at 1.4 K, the dc SQUID has a critical current of  $30 \mu\text{A}$ , as shown in Figure 3. This results in a 2D critical current per width of the

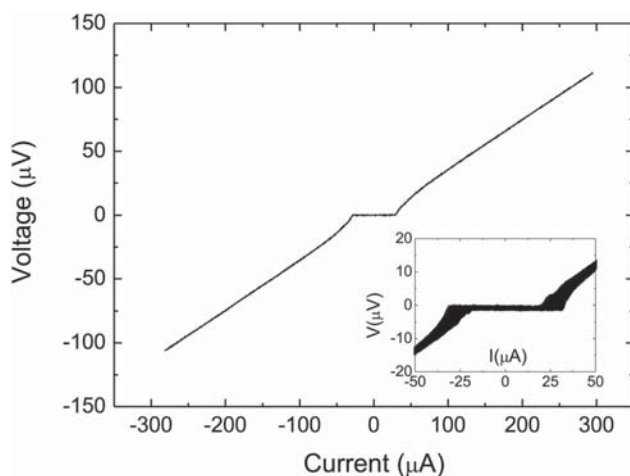


FIG. 3.  $IV$ -curve of the topological dc SQUID with a typical critical current of  $30 \mu\text{A}$ . The junctions are  $2 \mu\text{m}$  wide and have an electrode separation of 120 nm. The intrinsic bulk shunt has reduced the  $I_C R_N$  product to  $10 \mu\text{V}$ . Inset shows the  $IV$ -curve under magnetic field modulation.

junction of  $7.5 \text{ A/m}$ , which is within 10% of the individually measured critical current density of junctions on different flakes. The SQUID had a critical current constant within 10% over three cooldowns running over several weeks. Due to shunting of the junctions, we find a relative low  $I_C R_N = 10 \mu\text{V}$ . Ballistic junctions with  $\xi_T \approx 80 \text{ nm}$ ,  $T_C = 6 \text{ K}$ , and  $l = 120 \text{ nm}$  have an estimated  $I_C R_N \approx 130 - 260 \mu\text{V}$ , but the shunt due to the bulk conductance reduces the characteristic voltage to a few percent of the expected value,<sup>17</sup> consistent with the observed  $10 \mu\text{V}$ . In order to obtain higher  $I_C R_N$  values, electrical gating or chemical substitution, e.g.,  $\text{Bi}_2\text{Se}_2\text{Te}$ ,<sup>21</sup> could be used. The current-voltage characteristics are intrinsically non-hysteretic because of the low capacitance of the lateral geometry of the junctions and the high transparency of the interfaces.

Applying an external magnetic field causes oscillations of the superconducting critical currents due to interference of the two arms, shown in Fig. 4. This modulation of  $I_C$  unequivocally demonstrates the correct operation of the Nb- $\text{Bi}_2\text{Te}_3$  SQUID. The voltage modulation is strongest at a bias of approximately  $40 \mu\text{A}$ , which corresponds to a current close to the critical current of the SQUID. The critical current modulation is  $\sim 35\%$  of the total critical current. Using a simple model based on a sinusoidal current-phase relation of the junctions and taking inductance and possible asymmetries into account, we can fit the field dependence with high accuracy. The asymmetrical inductance causes an asymmetry in the SQUID current-phase relationship, see Fig. 4. We also observe a shift in the current-phase relationship when increasing the bias current. The two arms of the SQUID have different inductances and critical currents, which results in a growing field threading the SQUID for increasing current. The SQUID inductance  $L = \frac{\Phi_0 \beta_L}{2\pi I_c} = 55 \text{ pH}$  combined with the inductance asymmetry  $\lambda = 0.2$  give inductances  $L_1 = 9 \text{ pH}$  and  $L_2 = 46 \text{ pH}$ . At a bias current of  $90 \mu\text{A}$ , a current ratio through both arms of 1.1 is estimated using the critical current differences and assuming an equal normal state resistance. This results in a shift of  $0.74 \Phi_0$ , comparable to the observed shift of  $0.75 \Phi_0$ . At the optimum bias, the sensitivity of the SQUID is  $15 \mu\text{V}/\Phi_0$ . In the limit  $\beta_L (= 5) \gg 1$ , the sensitivity of a SQUID can be estimated by  $R/L$ <sup>22</sup> which yields  $12 \mu\text{V}/\Phi_0$ .

As expected, the SQUID modulation frequency is much larger than that of the individual junctions, see Fig. 4. A SQUID oscillation corresponds to  $1.9 \mu\text{T}$ , while the critical current of the junctions is suppressed at  $350 \mu\text{T}$ . This corresponds to about 180 SQUID oscillations in a junction oscillation, which is slightly lower than expected by comparing the enclosed areas. However, for the enclosed area of a junction, the Josephson penetration depth and flux focusing have to be included, which increases the junction effective area.<sup>17</sup>

Since the supercurrent is carried by topological surface states,<sup>17</sup> we can study the current-phase relationship of topological junctions by means of our dc SQUID. In a dc SQUID with topological insulator surface states as interlayers, the phase difference over the junctions due to a given field is equal to a standard SQUID. However, the presence of Majorana fermions can cause a  $I_C = I_0 \sin(\phi/2)$  junction current-phase relation, resulting in a  $4\pi$  periodic dependence of the junctions.<sup>11</sup> To test the periodicity of the SQUID, the

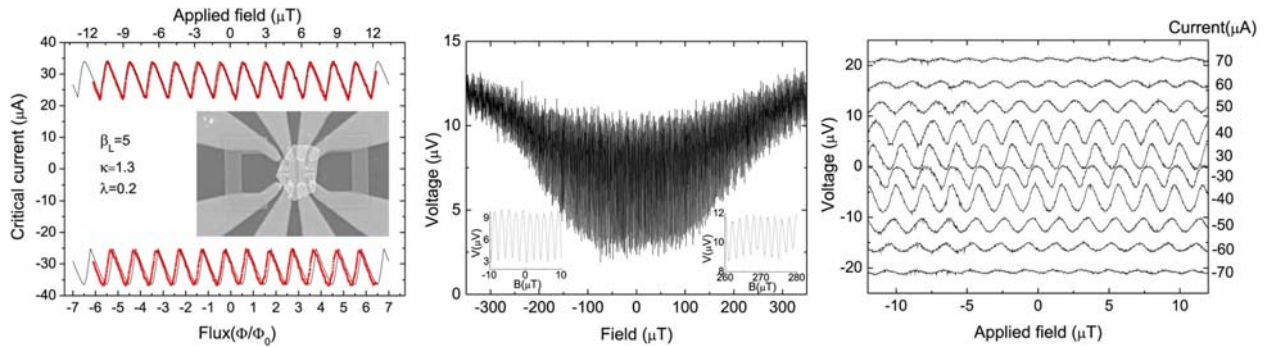


FIG. 4. (Color online) Voltage modulation the dc SQUID. (a) The critical current of the SQUID can be fitted (thin red line) by a model that accounts for the asymmetry of the design with fitting parameters,  $\beta_L = 5$ , the critical current ratio  $\kappa = 1.3$ , and inductance ratio  $\lambda = 0.2$ . (b) The critical current of the individual junctions is suppressed at  $350 \mu\text{T}$  (Fraunhofer pattern). SQUID oscillations are still observable. Inset shows the SQUID oscillations at small fields (left) and large fields (right) (c) The  $V-\phi$  relationship reveals an asymmetric response as well as a shift for increasing bias currents. The solid lines represent equicurrents for  $\pm 30\text{--}70 \mu\text{A}$ .

magnetic field from the coil is calibrated with a Hall sensor and the effective area of the SQUID,  $920 \mu\text{m}^2$ , is estimated using the square washer approximation.<sup>20</sup> A  $2\pi$  periodic dependence within 7% accuracy is calculated, enough to exclude  $4\pi$  periodicity. The absence of a  $4\pi$  periodic dependence might result from the absence of a ferromagnetic insulator (breaking time reversal symmetry) or due to relaxation to equilibrium states, as was predicted theoretically.<sup>23,24</sup>

In conclusion, we have demonstrated Nb-Bi<sub>2</sub>Te<sub>3</sub> SQUIDs. As shown previously,<sup>17</sup> the supercurrent is carried by the topological surface states, thereby allowing the study of the current-phase relationship of superconductor-topological insulator structures. From the  $V-\phi$  characteristics, we deduced a  $2\pi$  current-phase relationship. The high reproducibility allows the study of the noise properties of these devices in future experiments and to eventually include magnetic insulators in order to break time reversal symmetry to create Majorana bound states.

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